TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIII)

# SSM6N24TU

#### High Speed Switching Applications

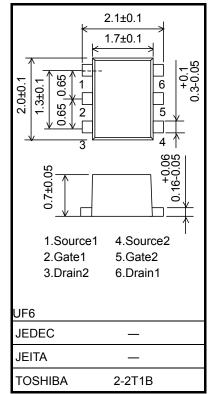
- Optimum for high-density mounting in small packages
- Low on-resistance:  $R_{on} = 145m\Omega (max) (@V_{GS} = 4.5 V)$  $R_{on} = 180m\Omega (max) (@V_{GS} = 2.5 V)$

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V <sub>DS</sub>	30	V	
Gate-Source voltage		V <sub>GSS</sub>	± 12	V	
Drain current	DC	۱ <sub>D</sub>	0.5	A	
	Pulse	I <sub>DP</sub>	1.5		
Drain power dissipation		P <sub>D</sub> (Note 1)	500	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

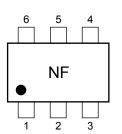


Weight: 7.0 mg (typ.)

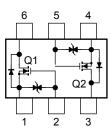
Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board. (total dissipation) (25.4 mm  $\times$  25.4 mm  $\times$  1.6 t, Cu Pad: 645 mm  $^2$  )

#### Marking



#### Equivalent Circuit (top view)



#### **Handling Precaution**

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Start of commercial production 2004-01

Unit: mm

Electrical Characteristics (Ta = 25°C)

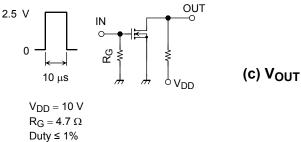
Chara	cteristics	Symbol	DI Test Condition		Тур.	Max	Unit	
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 12 V, V_{DS} = 0$	_		±1	μA	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	30			V	
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$	18	_	_	v	
Drain cut-off curre	nt	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0$	_	_	1	μA	
Gate threshold voltage		V <sub>th</sub>	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	0.5	_	1.1	V	
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.25 \text{ A}$ (Note2)	1.0	2.0	_	S	
Drain-Source on-resistance		R <sub>DS (ON)</sub>	$I_D = 0.50 \text{ A}, V_{GS} = 4.5 \text{ V} \qquad (\text{Note2})$	_	120	145	mΩ	
			$I_D = 0.25 \text{ A}, V_{GS} = 2.5 \text{ V} \qquad (\text{Note2})$	_	140	180		
Input capacitance		C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	245		pF	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		33		pF	
Output capacitance		C <sub>oss</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		41		pF	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 0.25 \text{ A},$	_	9			
	Turn-off time	t <sub>off</sub>	$V_{GS}$ = 0~2.5 V, $R_{G}$ = 4.7 $\Omega$	_	15	—	ns	

Note2: Pulse test

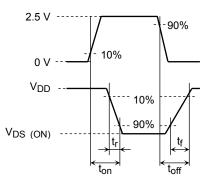
#### Switching Time Test Circuit

(a) Test Circuit

(b) V<sub>IN</sub>



Duty  $\leq 1\%$ V<sub>IN</sub>: t<sub>r</sub>, t<sub>f</sub> < 5 ns Common Source Ta = 25°C



#### Precaution

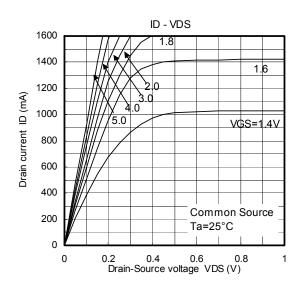
 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is I<sub>D</sub>=100  $\mu A$  for this product. For normal switching operation, V<sub>GS (on)</sub> requires a higher voltage than V<sub>th</sub> and V<sub>GS (off)</sub> requires a lower voltage than V<sub>th</sub>.

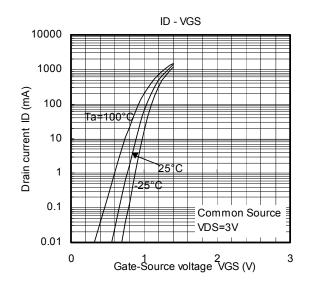
(The relationship can be established as follows:  $V_{GS (off)} < V_{th} < V_{GS (on)}$ )

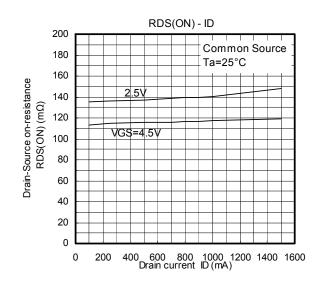
Please take this into consideration when using the device.

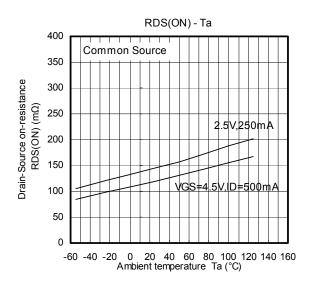
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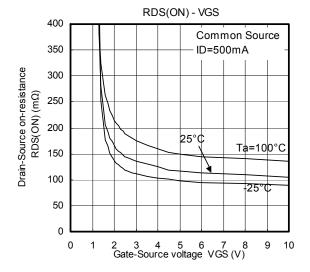
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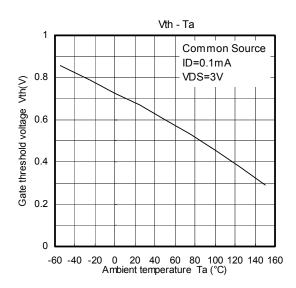








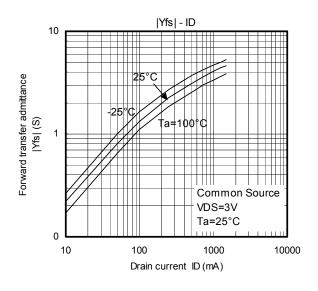


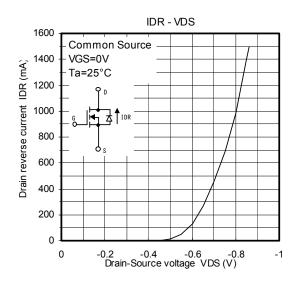


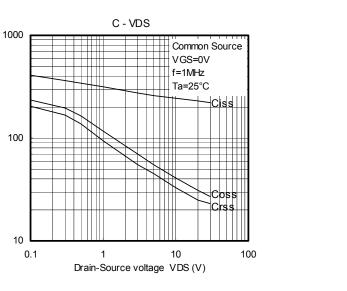
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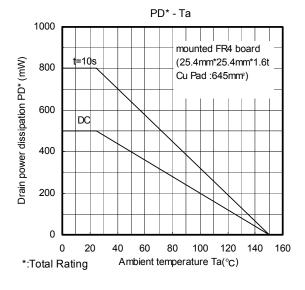
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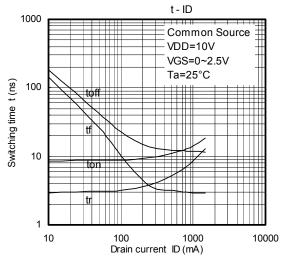
Capacitance C (pF)



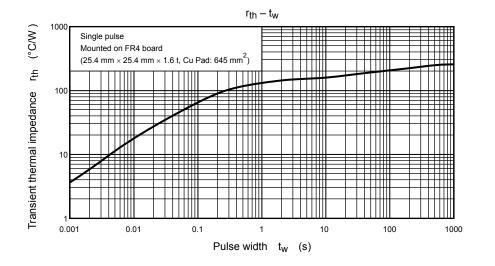








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